

# Assembly and characterization of a large area SiPM in Liquid Xenon Time Projection Chamber (LXe TPC)

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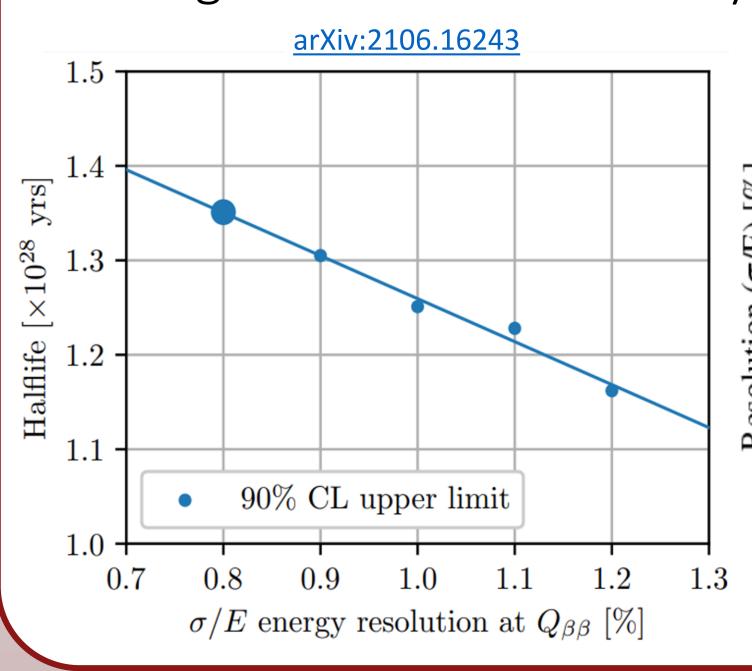
### The nEXO experiment

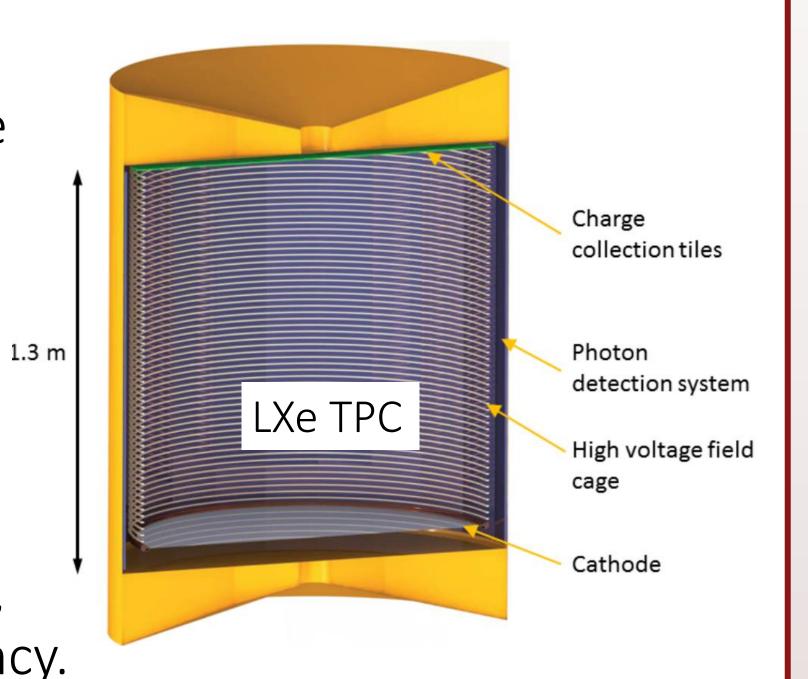
- 5 tonnes ~90% enriched <sup>136</sup>Xe TPC aiming to fully explore the neutrino Majorana mass in the inverted ordering
- Projected sensitivity to neutrinoless double beta decay after 10 years exposure (90% CL) >10<sup>28</sup>y

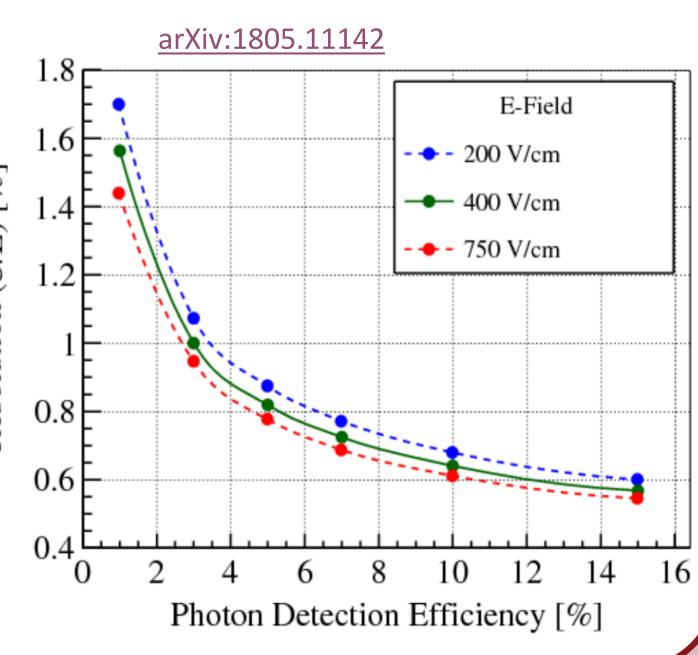
Three main observables are crucial to reach such result:

- Energy resolution
- Topology
- Event location

The resolution depends, among other parameters, on light collection efficiency.







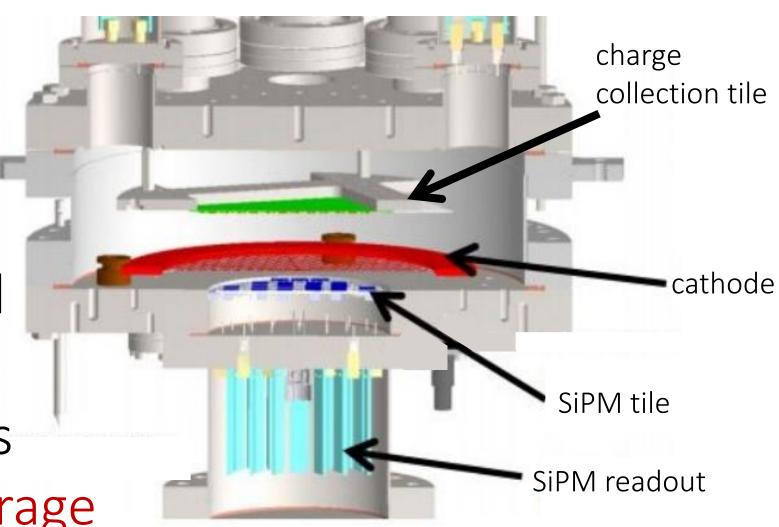
## Current Setup at Stanford

Mainly developed to characterize the charge tile [arXiv:1710.05109]

Light readout features:

- 24 1x1cm<sup>2</sup> SiPMs ganged into 12 channels
- Cold frontend electronics

Need for a larger light coverage to better study energy resolution



# Large Area SiPM Array Upgrade

# 8 fold increase in light- LX sensitive area:

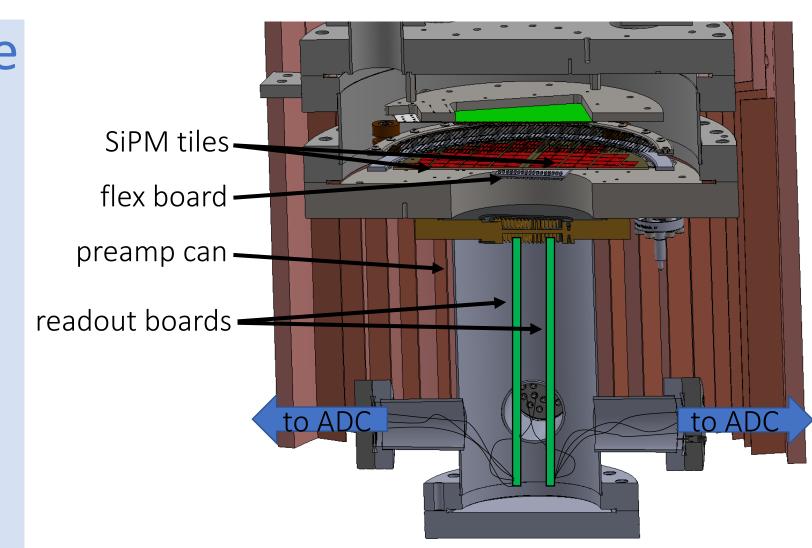
- SiPMs epoxied and wirebonded on two ceramic tiles
- 32 channels (gang of 6 SiPMs/ch)
- Signal carried out from the cell via Kapton flex boards

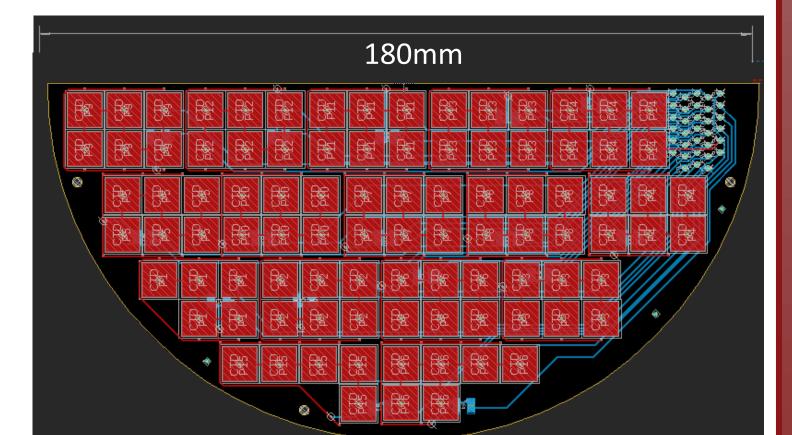
Signal is amplified with 2 readout boards

(16 channels each) Cold

Digitized with a 16bit ADC (125MS/s

sampling rate) Room

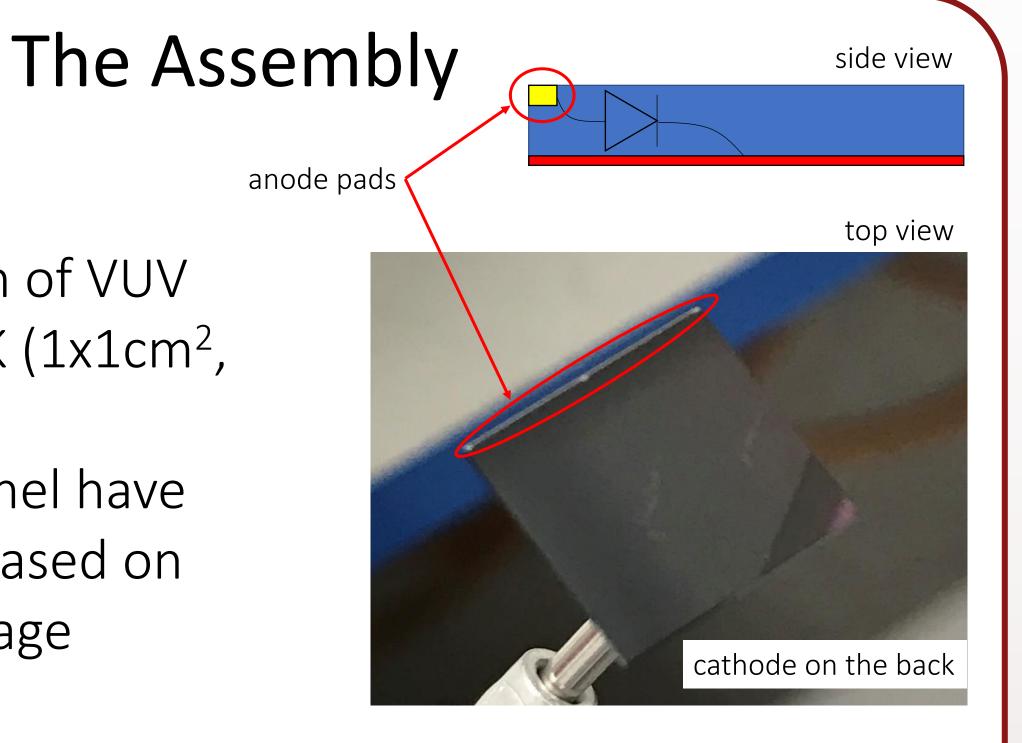




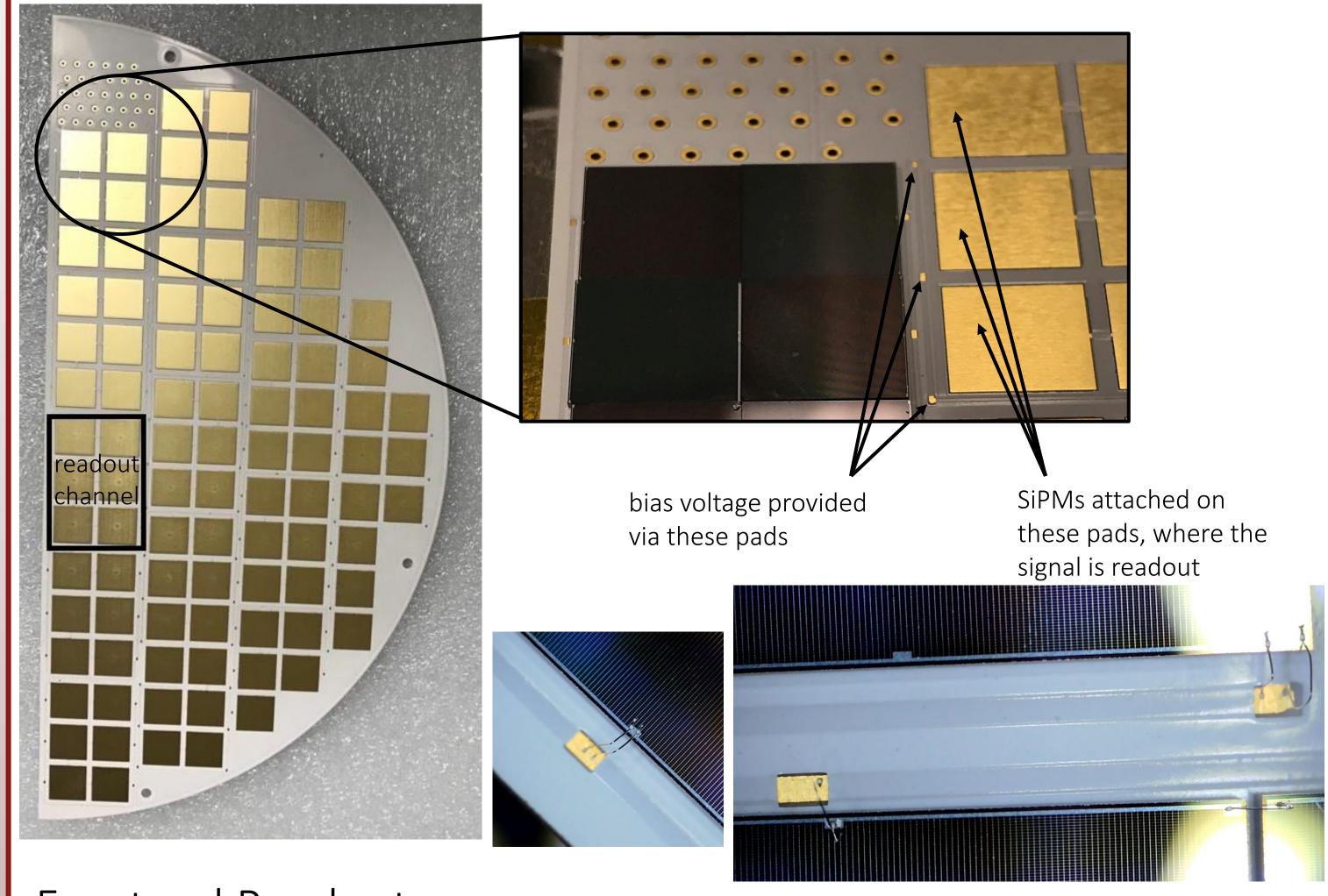
#### SiPM

Dedicated production of VUV sensitive SiPM by FBK ( $1x1cm^2$ ,  $375\mu m$  thick)

Devices in each channel have been gain-matched based on their breakdown voltage

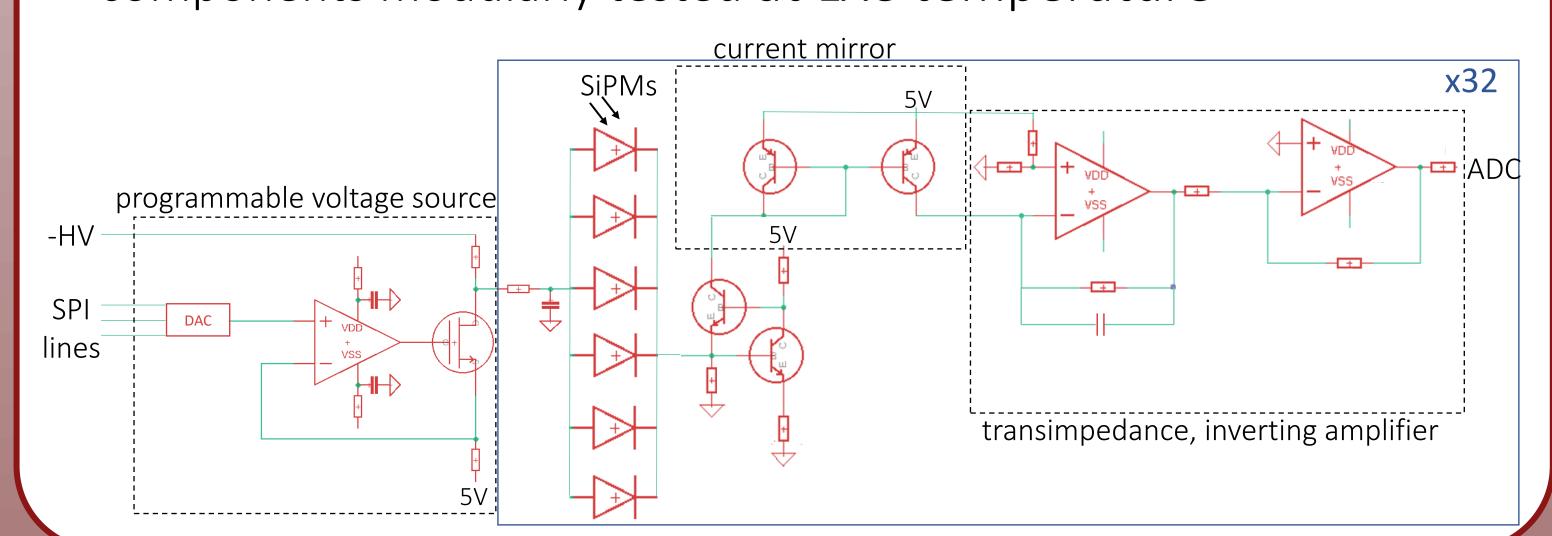


### Ceramic Tile



### Frontend Readout

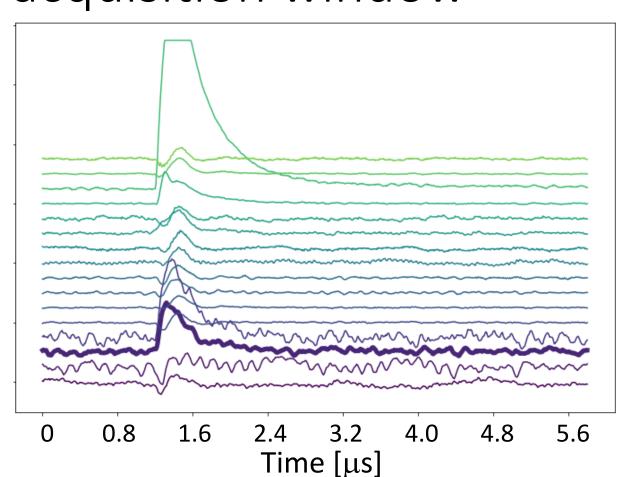
- programmable voltage to each channel (SiPMs input)
- 4x8 channels DACs daisy chained (SPI controlled) controlling the different biases -> only 4 wires controlling the 32 biases
- frontend amplifier for the signal (SiPMs output)
- components modularly tested at LXe temperature

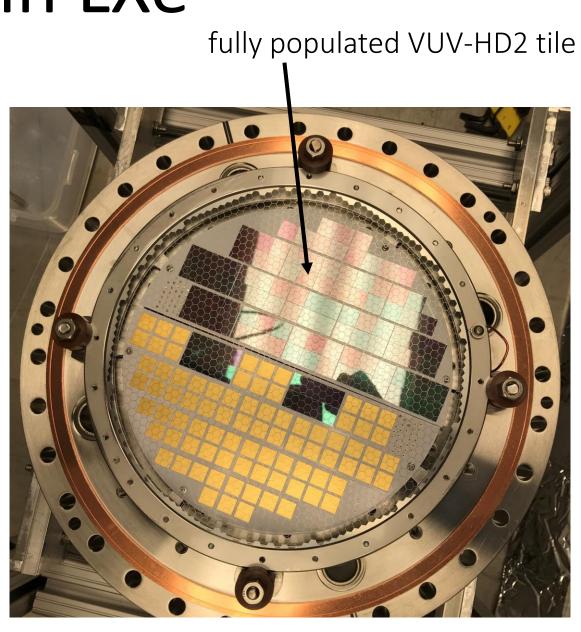


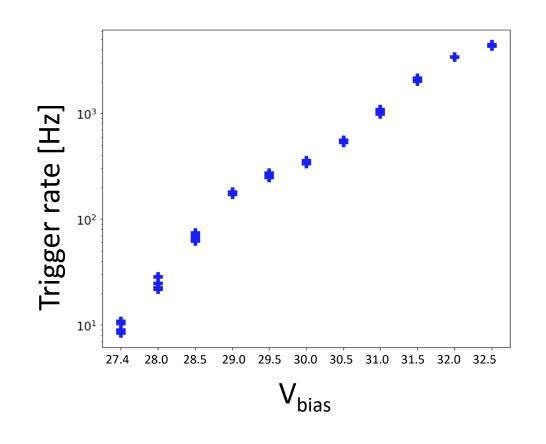
### First Test in LXe

Full end-to-end test carried out in LXe

- <sup>137</sup>Cs source outside the cryostat
- $V_{bias}$  swept from 27.4V to 32.5V
- OR threshold trigger on all 16 channels
- 6μs acquisition window







15<sup>TH</sup> Pisa Meeting on Advanced Detectors, La Biodola, May 22<sup>nd</sup>-28<sup>th</sup> 2022